FEATURES

- **High Slew Rate ..... 130V/µs Min**
- **Fast Settling Time (+10V, 0.1%) ..... 100ns Typ**
- **Gain-Bandwidth Product (A_{VCL} = +5) ..... 80MHz Typ**
- **Low Supply Current ..... 8mA Max**
- **Low Noise ..... 8nV/$\sqrt{Hz}$ Typ**
- **Low Offset Voltage ..... 1mV Max**
- **High Output Current ..... ±80mA Typ**
- **Eliminates External Buffer**
- **Standard 8-Pin Packages**
- **Available in Die Form**

ORDERING INFORMATION †

T_A = +25°C V_{OS} MAX (mV)	PACKAGE TO-99 8-PIN	HERMETIC DIP 8-PIN	PLASTIC 8-PIN	HERMETIC LCC 20-CONTACT	OPERATING TEMPERATURE RANGE
1.0	OP64AJ*	OP64AZ*	–	OP64ARC/883	MIL
1.0	OP64EJ	OP64EZ	–	–	XIND
2.0	OP64FJ	OP64FZ	–	–	XIND
2.5	–	–	OP64GP	–	XIND
2.5	–	–	OP64GS††	–	XIND

XIND = Extended Industrial Temperature Range, –40°C to +85°C

* For devices processed in total compliance to MIL-STD-883, add /883 after part number. Consult factory for 883 data sheet.

† Burn-in is available on commercial and industrial temperature range parts in CerDIP, plastic DIP, and TO-can packages. For ordering information, see PMI's Data Book, Section 2.

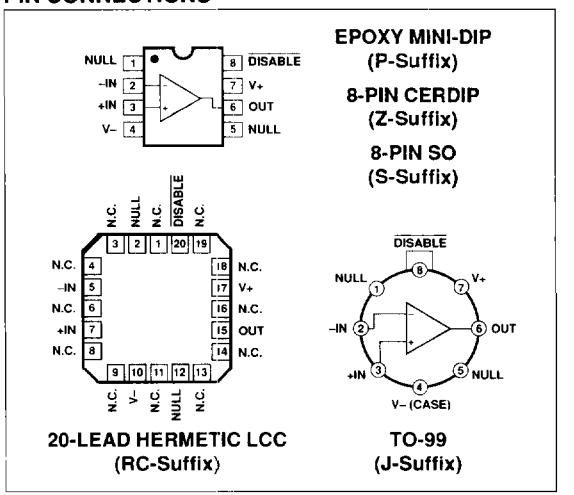
†† For availability and burn-in information on SO and PLCC packages, contact your local sales office.

GENERAL DESCRIPTION

The OP-64 is a high-performance monolithic operational amplifier that combines high speed and wide bandwidth with low power consumption. Advanced processing techniques have

Continued

PIN CONNECTIONS

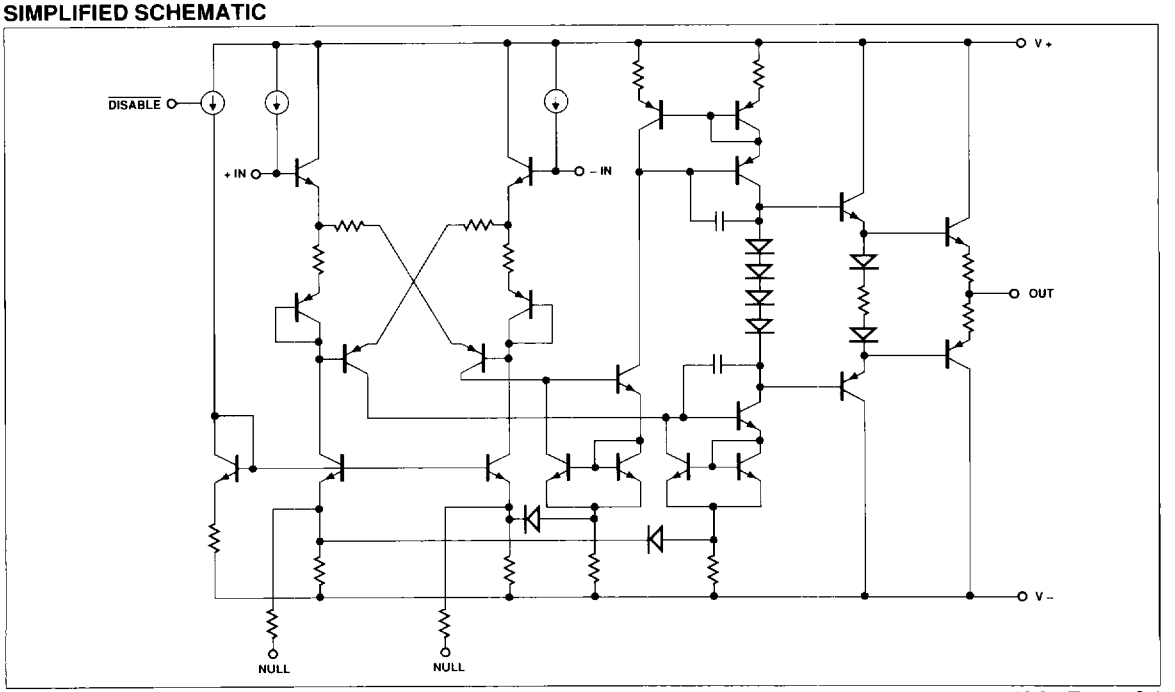


EPOXY MINI-DIP (P-Suffix)
8-PIN CERDIP (Z-Suffix)
8-PIN SO (S-Suffix)

20-LEAD HERMETIC LCC (RC-Suffix)

TO-99 (J-Suffix)

SIMPLIFIED SCHEMATIC



GENERAL DESCRIPTION *Continued*

enabled PMI to make the OP-64 superior in cost and performance to many dielectrically-isolated and hybrid op amps.

Slew rate of the OP-64 is over 130V/µs. It is stable in gains of ≥5 and has a settling time of only 100ns to 0.1% with a 10V step input. However, unlike other high-speed op amps which have high supply requirements, the OP-64 needs less than 8mA of supply current. This enables the OP-64 to be packaged in space saving 8-pin packages. The OP-64 can deliver ±80mA of output current eliminating the need for a separate buffer amplifier in many applications. Noise of the OP-64 is only 8nV$\sqrt{Hz}$, reducing system noise in wideband applications. In addition to its dynamic performance, the OP-64 adds DC precision with an input offset voltage of under 1mV.

The OP-64 is an ideal choice for RF, video and pulse amplifier applications and in new designs can replace the HA-5190/95 or EL-2190/95 with improved performance and reduced power consumption. Its high output current also suits the OP-64 for use in A/D or cable driver applications. The OP-64 includes a $\overline{\text{DISABLE}}$ pin which, when set low, shuts the amplifier off and reduces the supply current to 0.75mA.

ABSOLUTE MAXIMUM RATINGS (Note 1)

Supply Voltage ..... ±18V
Input Voltage ..... Supply Voltage
Differential Input Voltage 20V
$\overline{\text{DISABLE}}$ Input Voltage ..... Supply Voltage
Output Short-Circuit Duration ..... 10 sec
Storage Temperature Range
(J, Z, RC) ..... −65°C to +175°C
(P, S) ..... −65°C to +150°C
Operating Temperature Range
OP-64A (J, Z, RC) ..... −55°C to +125°C
OP-64E, F (J, Z) ..... −40°C to +85°C
OP-64G (P, S) ..... −40°C to +85°C
Maximum Junction Temperature
OP-64A (J ,Z, RC) ..... +175°C
OP-64E, F (J, Z) ..... +175°C
OP-64G (P, S) ..... +150°C
Lead Temperature (Soldering, 60 sec) ..... +300°C

PACKAGE TYPE	Θ_{JA} (Note 2)	Θ_{JC}	UNITS
TO-99 (J)	150	18	°C/W
8-Pin Hermetic DIP (Z)	148	16	°C/W
8-Pin Plastic DIP (P)	103	43	°C/W
20-Contact LCC (RC, TC)	98	38	°C/W
8-Pin SO (S)	158	43	°C/W

NOTES:
1. Absolute maximum ratings apply to both DICE and packaged parts, unless otherwise noted.
2. Θ_{JA} is specified for worst case mounting conditions, i.e., Θ_{JA} is specified for device in socket for TO, CerDIP, P-DIP, and LCC packages; Θ_{JA} is specified for device soldered to printed circuit board for SO package.

ELECTRICAL CHARACTERISTICS at V_S = ±15V, T_A = +25°C, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	OP-64A/E MIN	OP-64A/E TYP	OP-64A/E MAX	OP-64F MIN	OP-64F TYP	OP-64F MAX	OP-64G MIN	OP-64G TYP	OP-64G MAX	UNITS
Offset Voltage	V_{OS}		–	0.4	1	–	0.8	2	–	1.2	2.5	mV
Input Bias Current	I_B	V_{CM} = 0V	–	0.2	1	–	0.4	2	–	0.8	2.5	µA
Input Offset Current	I_{OS}	V_{CM} = 0V	–	0.1	1	–	0.3	2	–	0.6	2.5	µA
Input Voltage Range	IVR	(Note 1)	±11	–	–	±11	–	–	±11	–	–	V
Common-Mode Rejection	CMR	V_{CM} = ±11V	90	100	–	84	94	–	84	94	–	dB
Power-Supply Rejection Ratio	PSRR	V_S = ±5V to ±18V	–	5	17.8	–	15	31.6	–	15	31.6	µV/V
Large-Signal Voltage Gain	A_{VO}	R_L = 2kΩ, V_O = ±10V R_L = 200Ω, V_O = ±5V	30 12.5	45 18	– –	20 10	35 16	– –	20 10	35 16	– –	V/mV
Output Voltage Swing	V_O	R_L = 2kΩ R_L = 200Ω	±11 ±10	±12.5 ±11.7	– –	±11 ±10	±12.5 ±11.7	– –	±11 ±10	±12.5 ±11.7	– –	V
Output Current	I_{OUT}		–	±80	–	–	±80	–	–	±80	–	mA
Supply Current	I_{SY}	No Load	–	6.2	8	–	6.2	8	–	6.2	8	mA

NOTE:
1. Guaranteed by CMR test.

ELECTRICAL CHARACTERISTICS at V_S = ±15V, T_A = +25°C, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	OP-64A/E MIN	OP-64A/E TYP	OP-64A/E MAX	OP-64F MIN	OP-64F TYP	OP-64F MAX	OP-64G MIN	OP-64G TYP	OP-64G MAX	UNITS
Disable Supply Current	$I_{SY\ \overline{DIS}}$	$\overline{DISABLE}$ = 0V Total for both supplies	–	0.75	1	–	0.75	1	–	0.75	1	mA
$\overline{DISABLE}$ Current	$I_{\overline{DIS}}$	$\overline{DISABLE}$ = 0V	–	0.5	–	–	0.5	–	–	0.5	–	mA
Slew Rate	SR	R_L = 2kΩ	130	170	–	130	170	–	130	170	–	V/µs
Full-Power Bandwidth	BW_p	(Note 2)	2	2.7	–	2	2.7	–	2	2.7	–	MHz
Gain-Bandwidth Product	GBWP	A_V = +5	–	80	–	–	80	–	–	80	–	MHz
Settling Time	t_s	10V Step 0.1%	–	100	–	–	100	–	–	100	–	ns
Phase Margin	$ø_m$	A_V = +5	–	57	–	–	57	–	–	57	–	degrees
Input Capacitance	C_{IN}		–	5	–	–	5	–	–	5	–	pF
Open-Loop Output Resistance	R_O		–	30	–	–	30	–	–	30	–	Ω
Voltage Noise Density	e_n	f_o = 10Hz	–	30	–	–	30	–	–	30	–	nV/√Hz
		f_o = 100Hz	–	10	–	–	10	–	–	10	–	
		f_o = 1kHz	–	8	–	–	8	–	–	8	–	
		f_o = 10kHz	–	8	–	–	8	–	–	8	–	
Current Noise Density	i_n	f_o = 10kHz	–	7.5	–	–	7.5	–	–	7.5	–	pA/√Hz
External V_{OS} Trim Range	R_{pot} = 20kΩ		–	4	–	–	4	–	–	4	–	mV
Supply Voltage Range	V_S		±5	±15	±18	±5	±15	±18	±5	±15	±18	V

NOTES:
1. Guaranteed by CMR test.
2. Guaranteed by slew-rate test and formula $BW_p = SR/(2\pi 10V_{PEAK})$.

ELECTRICAL CHARACTERISTICS at $V_S = \pm15V$, $-40°C \le T_A \le +85°C$ for OP-64E/F/G, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	OP-64E MIN	OP-64E TYP	OP-64E MAX	OP-64F MIN	OP-64F TYP	OP-64F MAX	OP-64G MIN	OP-64G TYP	OP-64G MAX	UNITS
Offset Voltage	V_{OS}		–	0.5	1.5	–	1.0	3	–	1.5	3.5	mV
Input Bias Current	I_B	$V_{CM} = 0V$	–	0.3	2.5	–	0.5	3	–	1.5	3.5	µA
Input Offset Current	I_{OS}	$V_{CM} = 0V$	–	0.2	2.5	–	0.5	3	–	1.0	3.5	µA
Input Voltage Range	IVR	(Note 1)	±11	–	–	±11	–	–	±11	–	–	V
Common-Mode Rejection	CMR	$V_{CM} = \pm11$	86	100	–	80	94	–	80	94	–	dB
Power-Supply Rejection Ratio	PSRR	$V_S = \pm5V$ to $\pm18V$	–	5	31.6	–	15	50	–	15	50	µV/V
Large-Signal Voltage Gain	A_{VO}	$R_L = 2k\Omega$, $V_O = \pm10V$ $R_L = 200\Omega$, $V_O = \pm5V$	20 7.5	40 12	– –	15 5	35 10	– –	15 5	35 10	– –	V/mV
Output Voltage Swing	V_O	$R_L = 2k\Omega$ $R_L = 200\Omega$	±11 ±10	±12.3 ±11.5	– –	±11 ±10	±12.3 ±11.5	– –	±11 ±10	±12.3 ±11.5	– –	V
Supply Current	I_{SY}	No Load	–	6.3	8.5	–	6.3	8.5	–	6.3	8.5	mA

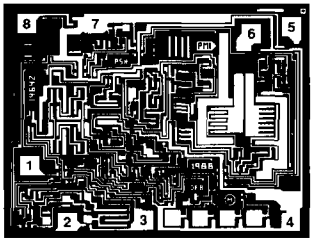
NOTE:
1. Guaranteed by CMR test.

ELECTRICAL CHARACTERISTICS at $V_S = \pm15V$, $-55°C \le T_A \le +125°C$ for OP-64A, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	OP-64A MIN	OP-64A TYP	OP-64A MAX	UNITS
Offset Voltage	V_{OS}		–	0.4	2	mV
Input Bias Current	I_B	$V_{CM} = 0V$	–	0.35	2	µA
Input Offset Current	I_{OS}	$V_{CM} = 0V$	–	0.3	2	µA
Input Voltage Range	IVR	(Note 1)	±11	–	–	V
Common-Mode Rejection	CMR	$V_{CM} = \pm11$	86	100	–	dB
Power-Supply Rejection Ratio	PSRR	$V_S = \pm5V$ to $\pm18V$	–	8	31.6	µV/V
Large-Signal Voltage Gain	A_{VO}	$R_L = 2k\Omega$, $V_O = \pm10V$ $R_L = 200\Omega$, $V_O = \pm5V$	20 7.5	30 10	– –	V/mV
Output Voltage Swing	V_O	$R_L = 2k\Omega$ $R_L = 200\Omega$	±11 ±7.5	±12 ±10	– –	V
Supply Current	I_{SY}	No Load	–	6.4	8.5	mA

NOTE:
1. Guaranteed by CMR test.

DICE CHARACTERISTICS



DIE SIZE 0.086 x 0.065 inch, 5,590 sq. mils (2.18 x 1.65 mm, 3.60 sq. mm)

1. NULL
2. –IN
3. +IN
4. V–
5. NULL
6. OUT
7. V+
8. $\overline{\text{DISABLE}}$

For additional DICE ordering information, refer to PMI's Data Book, Section 2.

WAFER TEST LIMITS at $V_S = \pm15V$, $T_A = +25°C$, unless otherwise noted.

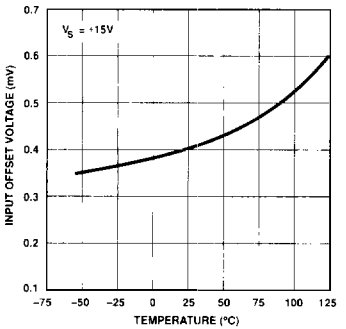
PARAMETER	SYMBOL	CONDITIONS	OP-64GBC LIMITS	UNITS
Offset Voltage	V_{OS}		2.5	mV MAX
Input Bias Current	I_B	$V_{CM} = 0V$	2.5	µA MAX
Input Offset Current	I_{OS}	$V_{CM} = 0V$	2.5	µA MAX
Input Voltage Range	IVR	(Note 1)	±11	V MIN
Common-Mode Rejection	CMR	$V_{CM} = +11V$	84	dB MIN
Power Supply Rejection Ratio	PSRR	$V_S = \pm5V$ to ±18V	31.6	µV/V MAX
Large-Signal Voltage Gain	A_{VO}	$R_L = 2k\Omega$, $V_O = \pm10V$ $R_L = 200\Omega$, $V_O = \pm5V$	20 10	V/mV MIN
Output Voltage Swing	V_O	$R_L = 2k\Omega$ $R_L = 200\Omega$	±11 ±10	V MIN
Slew Rate SR		$R_L = 2k\Omega$	120	V/µs MIN
Supply Current	I_{SY}	No Load	8	mA MAX

NOTES:
1. Guaranteed by CMR test.

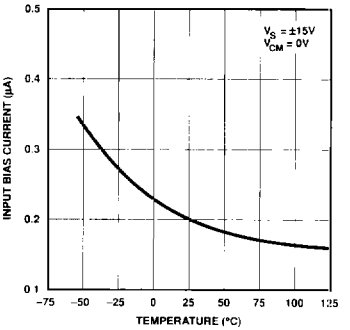
Electrical tests are performed at wafer probe to the limits shown. Due to variations in assembly methods and normal yield loss, yield after packaging is not guaranteed for standard product dice. Consult factory to negotiate specifications based on dice lot qualifications through sample lot assembly and testing.

TYPICAL PERFORMANCE CHARACTERISTICS

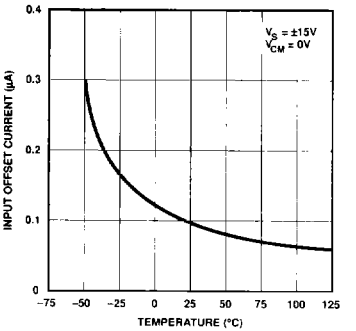
INPUT OFFSET VOLTAGE vs TEMPERATURE



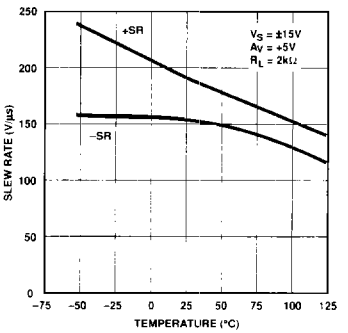
INPUT BIAS CURRENT vs TEMPERATURE



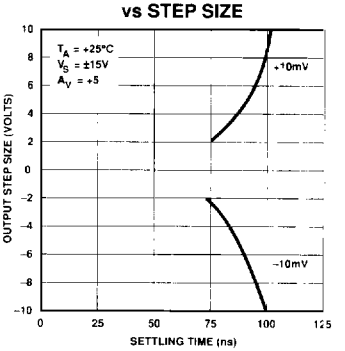
INPUT OFFSET CURRENT vs TEMPERATURE



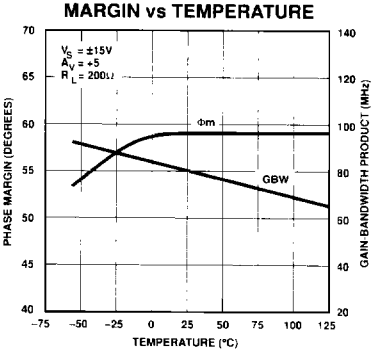
SLEW RATE vs TEMPERATURE



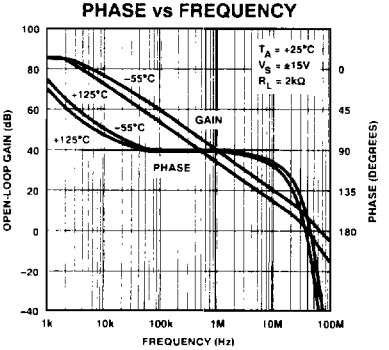
SETTLING TIME vs STEP SIZE



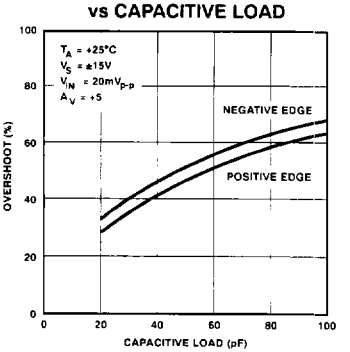
GAIN-BANDWIDTH PRODUCT, PHASE MARGIN vs TEMPERATURE



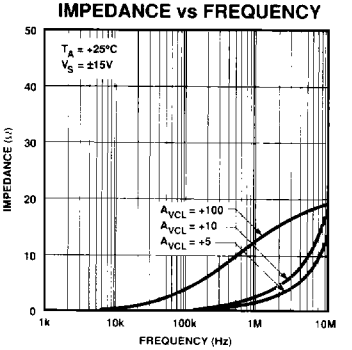
OPEN-LOOP GAIN, PHASE vs FREQUENCY



SMALL SIGNAL OVERSHOOT vs CAPACITIVE LOAD

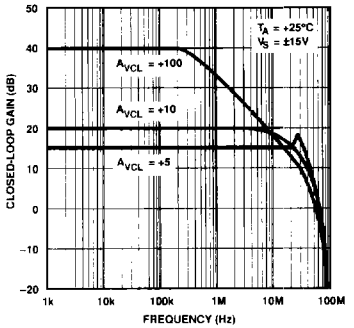


CLOSED-LOOP OUTPUT IMPEDANCE vs FREQUENCY

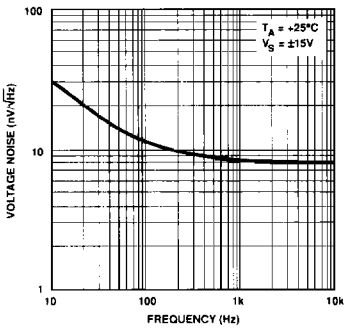


TYPICAL PERFORMANCE CHARACTERISTICS *Continued*

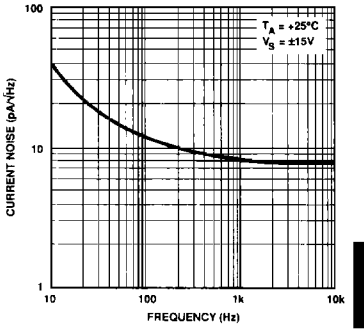
CLOSED-LOOP GAIN vs FREQUENCY



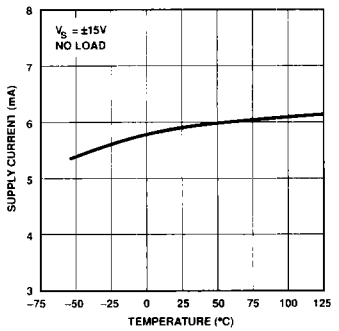
VOLTAGE NOISE DENSITY vs FREQUENCY



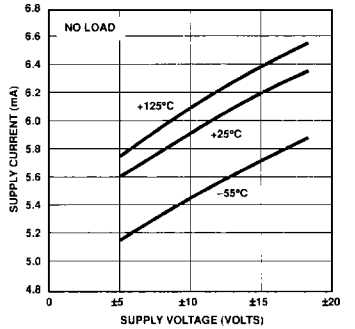
CURRENT NOISE DENSITY vs FREQUENCY



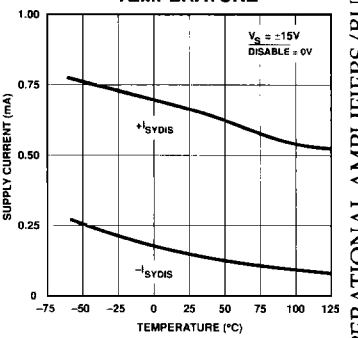
SUPPLY CURRENT vs TEMPERATURE



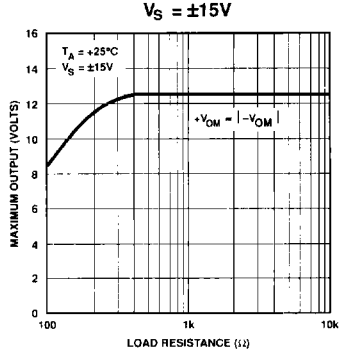
SUPPLY CURRENT vs SUPPLY VOLTAGE



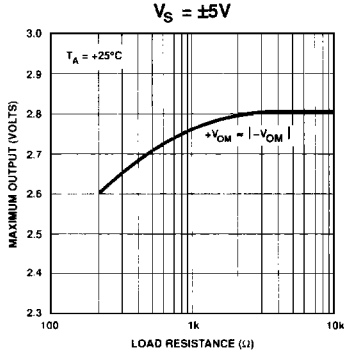
I_{SY} $\overline{\text{DISABLE}}$ vs TEMPERATURE



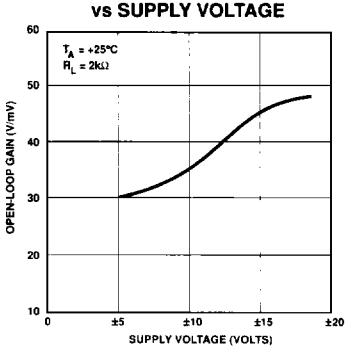
MAXIMUM OUTPUT VOLTAGE vs LOAD RESISTANCE V_S = ±15V



MAXIMUM OUTPUT VOLTAGE vs LOAD RESISTANCE V_S = ±5V

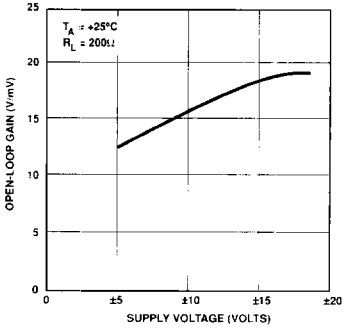


OPEN-LOOP GAIN vs SUPPLY VOLTAGE

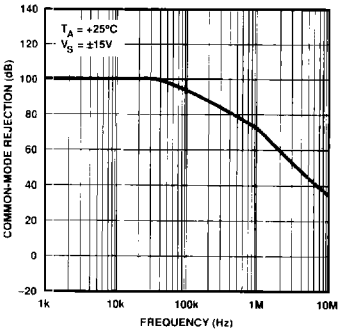


TYPICAL PERFORMANCE CHARACTERISTICS *Continued*

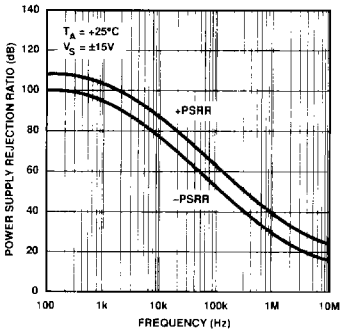
OPEN-LOOP GAIN vs SUPPLY VOLTAGE



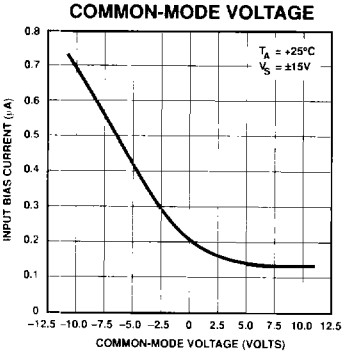
COMMON-MODE REJECTION vs FREQUENCY



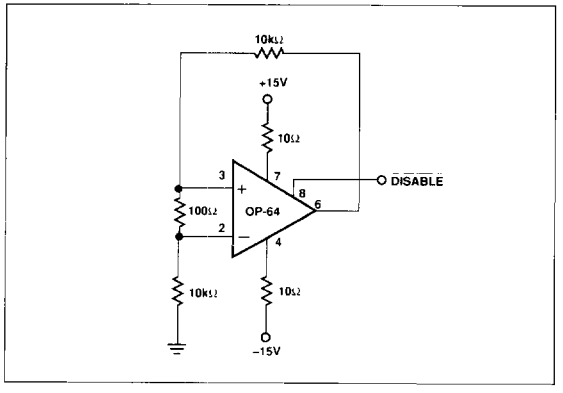
POWER SUPPLY REJECTION RATIO vs FREQUENCY



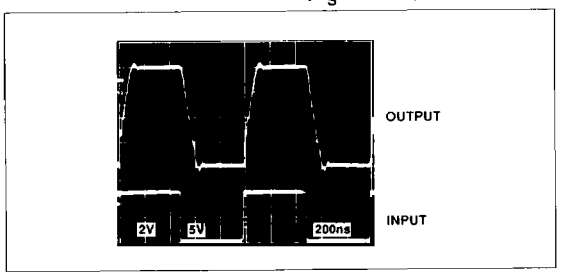
INPUT BIAS CURRENT vs COMMON-MODE VOLTAGE



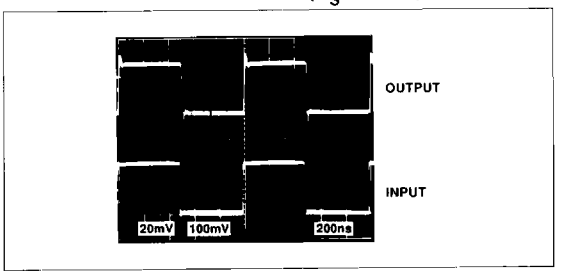
BURN-IN CIRCUIT



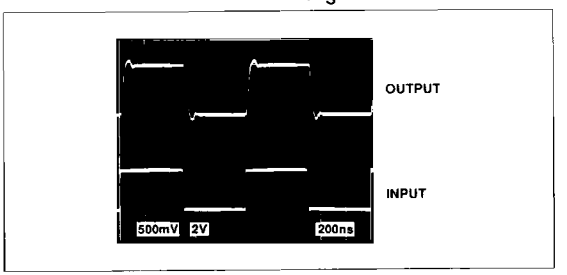
LARGE SIGNAL RESPONSE (V_S = ±15V)



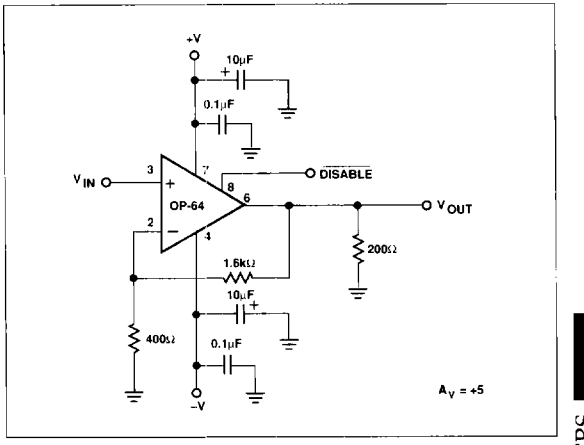
SMALL SIGNAL RESPONSE (V_S = ±15V)



LARGE SIGNAL RESPONSE (V_S = ±5V)



LARGE AND SMALL SIGNAL RESPONSE TEST CIRCUIT



APPLICATIONS INFORMATION

POWER SUPPLY BYPASSING AND LAYOUT CONSIDERATIONS

Proper power supply bypassing is critical in all high-frequency circuit applications. For stable operation of the OP-64, the power supplies must maintain a low impedance-to-ground over an extremely wide bandwidth. This is most critical when driving a low resistance or large capacitance, since the current required to drive the load comes from the power supplies. A 10µF and 0.1µF ceramic bypass capacitor are recommended for each supply, as shown in Figure 1, and will provide adequate high-frequency bypassing in most applications. The bypass capacitors should be placed at the supply pins of the OP-64. As with all high frequency amplifiers, circuit layout is a critical factor in obtaining optimum performance from the OP-64. Proper high frequency layout reduces unwanted signal coupling in the circuit. When breadboarding a high frequency circuit, use direct point-to-point wiring, keeping all lead lengths as short as possible. Do not use wire-wrap boards or "plug-in" prototyping boards.

During PC board layout, keep all lead lengths and traces as short as possible to minimize inductance. The feedback and gain-setting resistors should be as close as possible to the inverting input to reduce stray capacitance at that point. To further reduce stray capacitance, remove the ground plane from the area around the inputs of the OP-64. Elsewhere, the use of a solid unbroken ground plane will insure a good high-frequency ground.

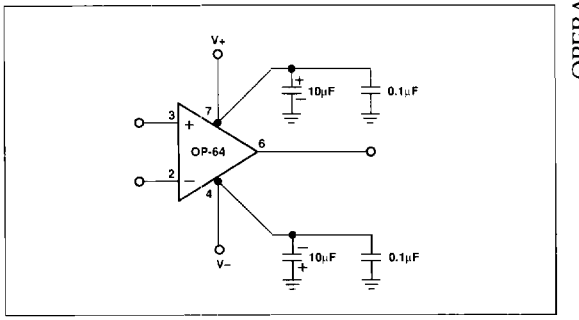


FIGURE 1: *Proper power supply bypassing is required to obtain optimum performance with the OP-64.*

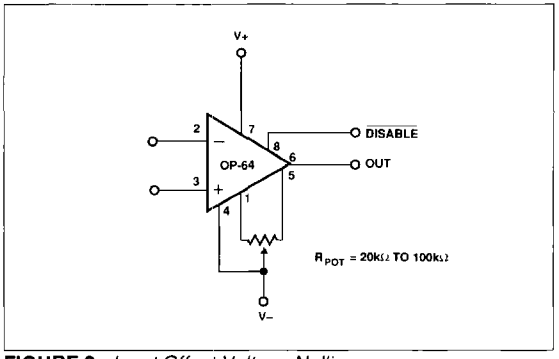


FIGURE 2: *Input Offset Voltage Nulling*

OFFSET VOLTAGE ADJUSTMENT

Offset voltage is adjusted with a 20kΩ potentiometer as shown in Figure 2. The potentiometer should be connected between pins 1 and 5 with its wiper connected to the V– supply. The typical trim range is ±4mV.

OP-64 $\overline{\text{DISABLE}}$ AMPLIFIER SHUTDOWN

Pin 8 of the OP-64, $\overline{\text{DISABLE}}$, is an amplifier shutdown control input. The OP-64 operates normally when Pin 8 is left floating. When greater than 250µA is drawn from the $\overline{\text{DISABLE}}$ pin, the OP-64 is disabled. The supply current drops to 1mA and the output impedance rises to 2kΩ. To draw current from the $\overline{\text{DISABLE}}$ pin, an open collector output logic gate or a discrete NPN transistor can be used as shown in Figure 3. An internal resistor limits the $\overline{\text{DISABLE}}$ current to around 500µA if the $\overline{\text{DISABLE}}$ pin is grounded with the OP-64 powered by ±15V supplies. These logic interface methods have the added advantage of level shifting the TTL signal to whatever supply voltage is used to power the OP-64.

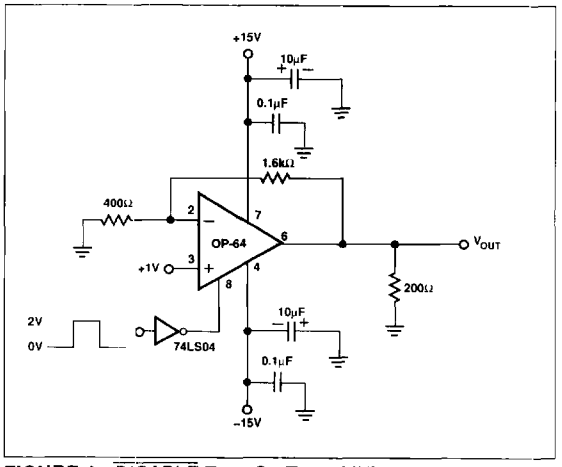


FIGURE 4: *$\overline{\text{DISABLE}}$ Turn-On/Turn-Off Test Circuit*

Figure 4 shows a test circuit for measuring the turn-on and turn-off times for the OP-64. The OP-64 is in a gain of 5 with a +1V DC input. As the input pulse to the 74LS04 rises its output falls,

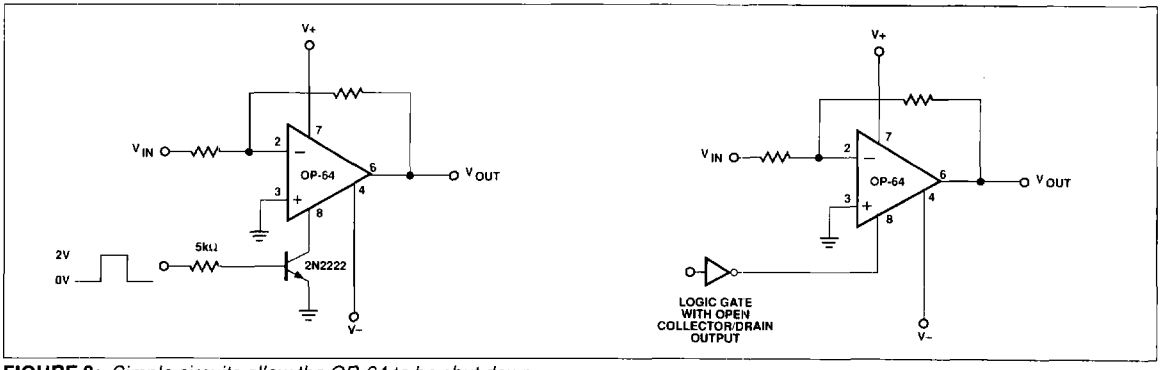


FIGURE 3: *Simple circuits allow the OP-64 to be shut down.*

drawing current from the $\overline{\text{DISABLE}}$ pin and disabling the amplifier. The output voltage delay is shown in Figure 5 and takes 500µs to reach ground due to the extra current supplied to the amplifier by the 10µF electrolytic bypass capacitors. The turn-on time is much quicker than the turn-off time. In this situation as the input to the 74LS04 falls its output rises, returning the OP-64 to normal operation. The amplifier's output turns on in 250ns.

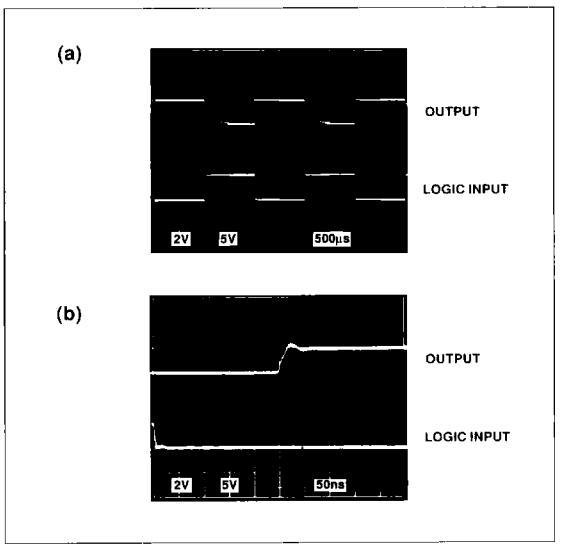


FIGURE 5: *(a) OP-64 turn-on and turn-off performance. (b) Expanded scale showing turn-on performance of the OP-64.*

OVERDRIVE RECOVERY

Figure 6 shows the overdrive recovery performance of the OP-64. Typical recovery time is 270ns from negative overdrive and 80ns from positive overdrive.

VIDEO AMPLIFIER/TERMINATED LINE DRIVER

The OP-64 can be used as a video amplifier/terminated line driver as shown in Figure 8. With its high output current capability, the OP-64 eliminates the need for an external buffer.

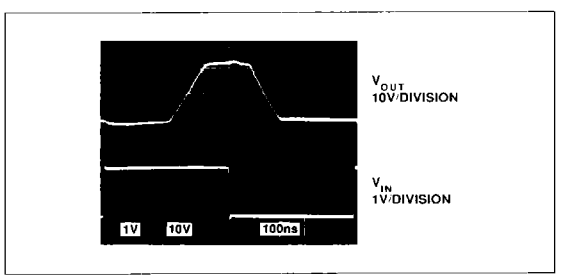


FIGURE 6: *OP-64 Overdrive Recovery*

The 75Ω cable termination resistor minimizes reflections from the end of the cable. The 75Ω series output resistor absorbs any reflections caused by a mismatch between the 75Ω termination resistor and the characteristic cable impedance. In this circuit the output voltage, V_{OUT}, is one-half of the OP-64's output voltage due to the divider formed by the 75Ω terminating resistors. The output voltage at the end of the terminated cable, V_{OUT}, spans –1V to +1V. The differential gain and phase for the video amplifier is summarized in Table1.

TABLE 1: Differential Gain and Phase of Video Amplifier/Line Driver

	Differential Gain		Differential Phase	
V_S	3.58MHz	5MHz	3.58MHz	5MHz
±15V	0.008dB	0.016dB	0.03°	0.03°
±12V	0.008dB	0.018dB	0.03°	0.03°

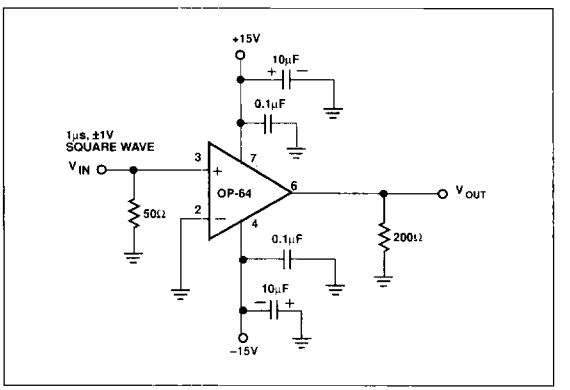


FIGURE 7: *Overdrive Recovery Test Circuit*

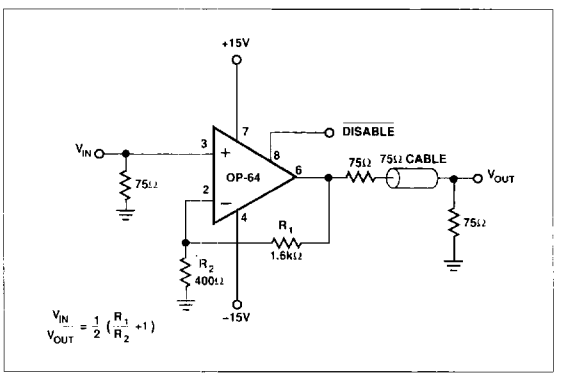


FIGURE 8: *Video Amplifier/Terminated Line Driver*

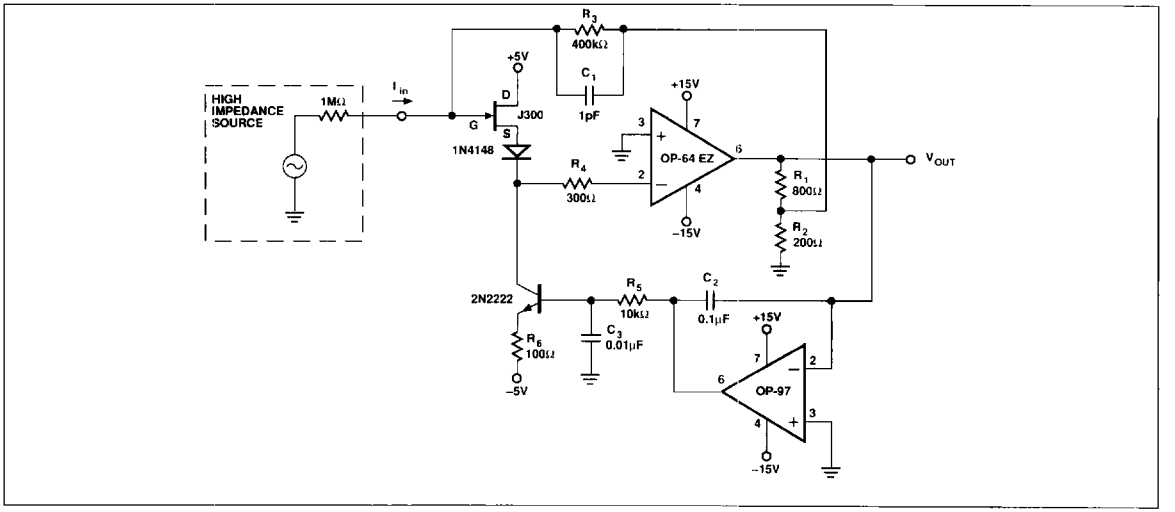


FIGURE 9: *Fast Transimpedance Amplifier*

FAST TRANSIMPEDANCE AMPLIFIER

The circuit shown in Figure 9 is a fast transimpedance amplifier designed to handle high speed signals from a high impedance source such as the output of a photomultiplier tube. The input current is amplified and converted to an output voltage by the transimpedance amplifier.

A JFET source-follower input is used to reduce the input bias current of the amplifier to 100 pA and lower the input current noise. Transimpedance of the amplifier is:

$$\frac{V_{OUT}}{I_{IN}} = \left(\frac{R_1}{R_2} + 1\right) R_3$$

and for the values shown equals

$$\frac{V_{OUT}}{I_{IN}} = \left(\frac{800\Omega}{200\Omega} + 1\right) 400k\Omega = 2V/\mu A$$

Figure 10 shows the output of the transimpedance amplifier when driven from a 1MΩ source impedance. The input signal of $10\mu A_{p\text{-}p}$ is converted into an output voltage of (10μA) 2V/μA = $20V_{p\text{-}p}$. Output slew rate is 100V/μs. The slew rate is limited by the combination of the capacitance of the JFET gate with the 1MΩ source impedance. For best performance, the stray input capacitance should be kept as small as possible. The OP-97 is used in an integrator loop to reduce the total amplifier offset voltage to under 25μV.

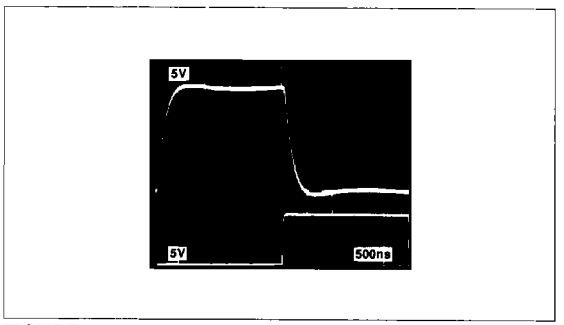


FIGURE 10: *Output of the Fast Transimpedance Amplifier*

OP-64 SPICE MACRO-MODEL

Figure 11 shows the node and net list for a SPICE macro-model of the OP-64. The model is a simplified version of the actual device and simulates important DC parameters such as V_{OS}, I_{OS}, I_B, A_{VO}, CMR, V_O and I_{SY}. AC parameters such as slew rate, gain and phase response and CMR change with frequency are also simulated by the model.

The model uses typical parameters for the OP-64. The poles and zeros in the model were determined from the actual open and closed-loop gain and phase response of the OP-64. In this way the model presents an accurate AC representation of the actual device. The model assumes an ambient temperature of 25°C (see following pages).

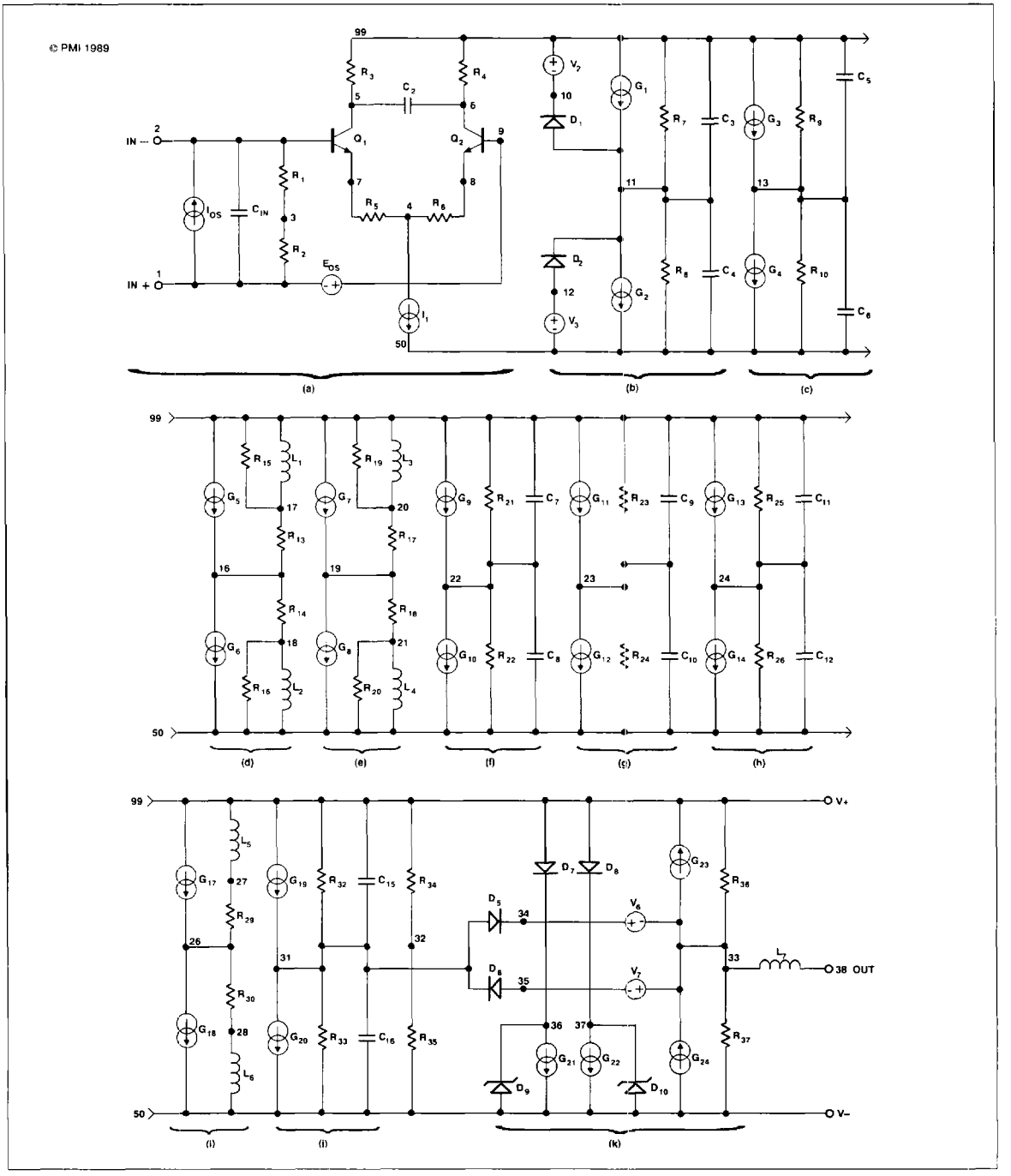


FIGURE 11a: *OP-64 SPICE Macro-Model Schematic and Node List*

```
OP-64 MACRO-MODEL © PMI 1989
*
* subckt OP-64 1  2 38  99  50
*
INPUT STAGE & POLE AT 39.8 MHz
*
r1   2    3          5E11
r2   1    3          5E11
r3   5    99         474.86
r4   6    99         474.86
r5   4    7          423.26
r6   4    8          423.26
cin  1    2          5E-12
c2   5    6          4.2106E-12
i1   4    50         1E-3
ios  1    2          1E-7
eos  9    1          poly(1) 26 32 4E-4 1
q1   5    2    7     qx
q2   6    9    8     qx
*
* SECOND STAGE & POLE AT 3.8 kHz
*
r7   11   99         7.1229E6
r8   11   50         7.1229E6
c3   11   99         5.88E-12
c4   11   50         5.88E-12
g1   99   11         poly(1) 5 6 4.31E-3 2.1059E-3
g2   11   50         poly(1) 6 5 4.31E-3 2.1059E-3
v2   99   10         2.25
v3   12   50         2.25
d1   11   10         dx
d2   12   11         dx
*
* POLE AT 39.8 MHz
*
r9   13   99         1E6
r10  13   50         1E6
c5   13   99         4E-15
c6   13   50         4E-15
g3   99   13         11 32 1E-6
g4   13   50         32 11 1E-6
*
* ZERO-POLE PAIR AT 26.5 MHz /159 MHz
*
r13  16   17         1E6
r14  16   18         1E6
r15  17   99         5E6
r16  18   50         5E6
l1   17   99         5.005E-3
l2   18   50         5.005E-3
g5   99   16         13 32 1E-6
g6   16   50         32 13 1E-6
*
* ZERO-POLE PAIR AT 31.8 MHz / 39.8 MHz
*
r17  19   20         1E6
r18  19   21         1E6
r19  20   99         2.5157E5
r20  21   50         2.5157E5
l3   20   99         1.006E-3
l4   21   50         1.006E-3
g7   99   19         16 32 1E-6
g8   19   50         32 16 1E-6
*
* POLE AT 100 MHz
*
r21  22   99         1E6
r22  22   50         1E6
c7   22   99         1.59E-15
c8   22   50         1.59E-15
g9   99   22         19 32 1E-6
g10  22   50         32 19 1E-6
*
*POLE AT 159 MHz
*
r23  23   99         1E6
r24  23   50         1E6
c9   23   99         1E-15
c10  23   50         1E-15
g11  99   23         22 32 1E-6
g12  23   50         32 22 1E-6
*
*POLE AT 159 MHz
*
r25  24   99         1E6
r26  24   50         1E6
c11  24   99         1E-15
c12  24   50         1E-15
g13  99   24         23 32 1E-6
g14  24   50         32 23 1E-6
*
*COMMON-MODE GAIN NETWORK WITH ZERO AT 20kHz
*
r29  26   27         1E6
r30  26   28         1E6
l5   27   99         7.9575
l6   28   50         7.9575
g17  99   26         33 32 1E-11
g18  26   50         32 33 1E-11
*
* POLE AT 159 MHz
*
r32  31   99         1E6
r33  31   50         1E6
c15  31   99         1E-15
c16  31   50         1E-15
g19  99   31         24 32 1E-6
g20  31   50         32 24 1E-6
*
* OUTPUT STAGE
*
r34  32   99         20.0E3
r35  32   50         20.0E3
r36  33   99         60
r37  33   50         60
l7   33   38         2.9E-7
g21  36   50         31  33   16.6666667E-3
g22  37   50         33  31   16.6666667E-3
g23  33   99         99  31   16.6666667E-3
g24  50   33         31  50   16.6666667E-3
v6   34   33         1.7
v7   33   35         1.7
d5   31   34         dx
d6   35   31         dx
d7   99   36         dx
d8   99   37         dx
d9   50   36         dy
d10  50   37         dy
*
* MODELS USED
*
.model qx NPN(BF=2500)
.model dx    D(IS=1E-15)
.model dy    D(IS=1E-15 BV=50)
.ends OP-64
```

FIGURE 11b: *OP-64 SPICE Net-List*